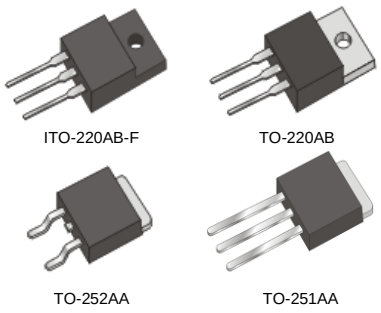
PANJIT SEMICONDUCTOR

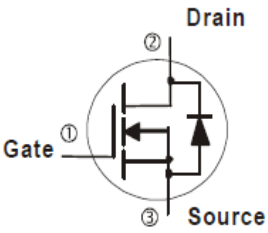
Preliminary

PJU45N06A / PJD45N06A / PJP45N06A / PJF45N06A

60V N-Channel Enhancement Mode MOSFET

Voltage	60 V	Current	45 A





Features

- $R_{DS(ON)}$, V_{GS}@10V,I_D@20A<12mΩ
- $R_{DS(ON)}$, V_{GS}@4.5V,I_D@15A<15mΩ
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case : TO-251AA, TO-252AA,TO-220AB, ITO-220AB-F Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.067 ounces, 1.9 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	TO-251AA	TO-220AB	ITO-220AB-F	TO-252AA	UNITS
Drain-Source Voltage		V_{DS}	60				V
Gate-Source Voltage		V_{GS}	±20				V
Continuous Drain Current	T_C=25°C	I_D	45				A
	T_C=100°C		29				
Pulsed Drain Current (Note 1)	T_C=25°C	I_{DM}	180				A
Power Dissipation	T_C=25°C	P_D	63	78	28	63	W
	T_C=100°C		25	31	11	25	
Continuous Drain Current	T_A=25°C	I_D	9.5				A
	T_A=70°C		7.6				
Power Dissipation	T_A=25°C	P_D	1.1	2.0	1.0	1.1	W
Power Dissipation	T_A=70°C		0.7	1.3	0.7	0.7	
Single Pulse Avalanche Energy (Note 6)		E_{AS}	61				mJ
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150				°C
Typical Thermal resistance (Note 4,5)							°C/W
- Junction to Case		$R_{\theta JC}$	2	1.6	4.5	2	
- Junction to Ambient		$R_{\theta JA}$	110	62.5	120	110	

- Limited only By Maximum Junction Temperature

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V,I_D=250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS},I_D=250uA	1	1.7	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=10V,I_D=20A	-	10.5	12	mΩ
		V_{GS}=4.5V,I_D=15A	-	12	15	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=60V,V_{GS}=0V	-	-	1.0	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V,V_{DS}=0V	-	-	±100	nA
Dynamic (Note 7)						
Total Gate Charge	Q_g	V_{DS}=30V, I_D=10A, V_{GS}=10V (Note 2,3)	-	39	-	nC
Gate-Source Charge	Q_{gs}		-	6.1	-	
Gate-Drain Charge	Q_{gd}		-	6.7	-	
Input Capacitance	Ciss	V_{DS}=25V, V_{GS}=0V, f=1.0MHZ	-	2256	-	pF
Output Capacitance	Coss		-	145	-	
Reverse Transfer Capacitance	Crss		-	93	-	
Turn-On Delay Time	$td_{(on)}$	V_{DS}=15V,I_D=10A, V_{GS}=10V, R_G=6Ω (Note 2,3)	-	7.5	-	ns
Turn-On Rise Time	t_r		-	36	-	
Turn-Off Delay Time	$td_{(off)}$		-	49	-	
Turn-Off Fall Time	t_f		-	12	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	45	A
Diode Forward Voltage	V_{SD}	I_S=1A,V_{GS}=0V	-	0.67	1.0	V

NOTES :

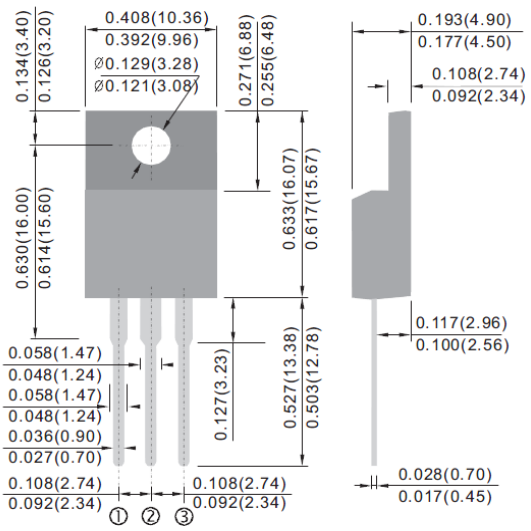
1. Pulse width≤300us, Duty cycle≤2%
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
4. The maximum current rating is package limited.
5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 $inch^2$ with 2oz.square pad of copper.
6. The test condition is L=0.1mH, I_{AS}=35A, V_{DD}=25V, V_{GS}=10V, R_G=25ohm, Starting T_J=25°C
7. Guaranteed by design, not subject to production testing.

PJU45N06A / PJD45N06A / PJP45N06A / PJF45N06A

Packaging Information

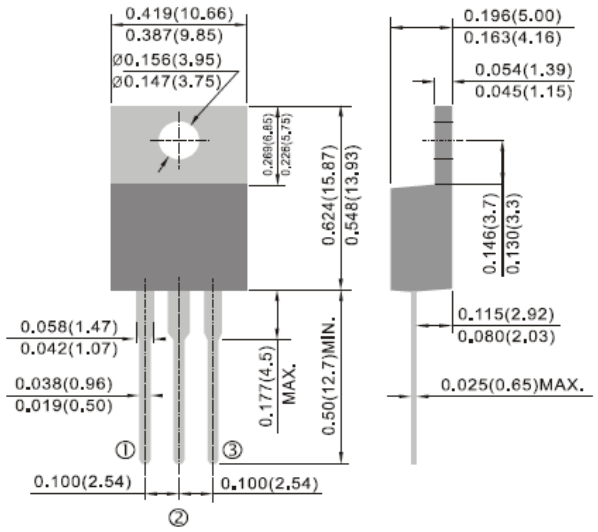
ITO-220AB-F Dimension

Unit: mm



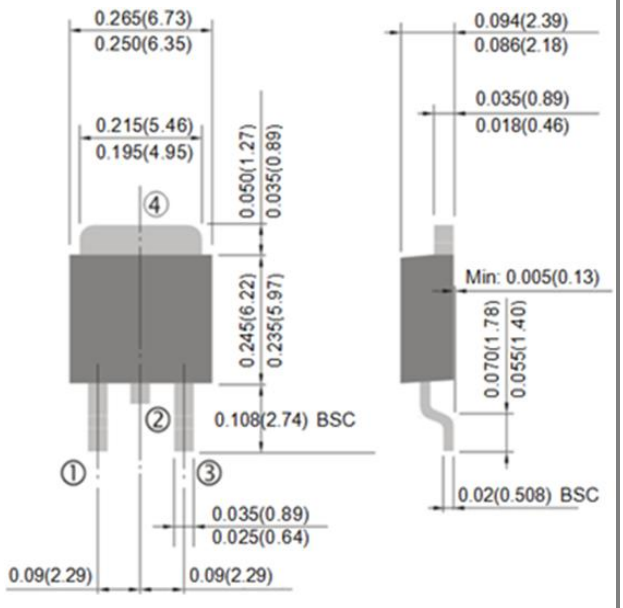
TO-220AB Dimension

Unit: mm



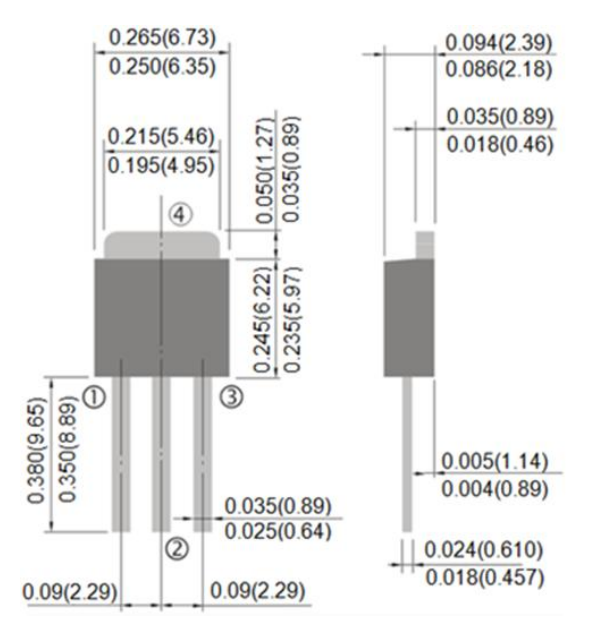
TO-252AA Dimension

Unit: mm



TO-251AA Dimension

Unit: mm



PJU45N06A / PJD45N06A / PJP45N06A / PJF45N06A

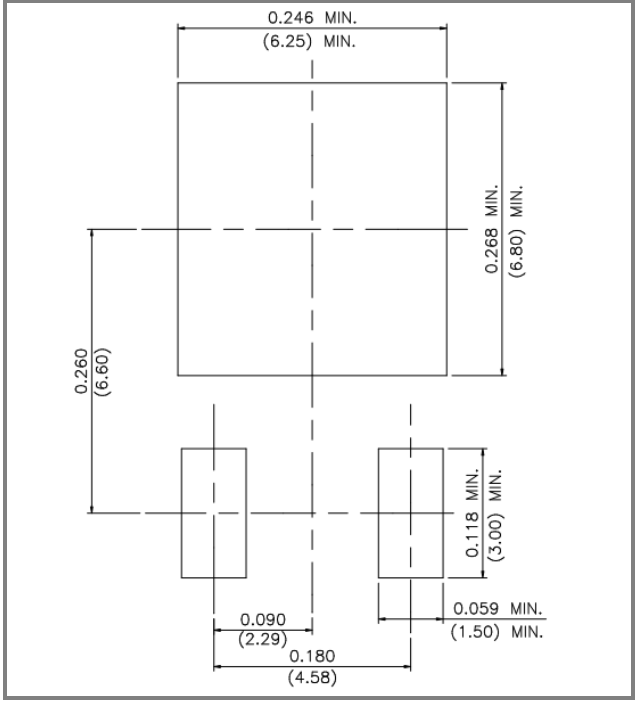
PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJD45N06A_L2_00001	TO-252AA	3,000pcs / 13” reel	D45N06A	Halogen free
PJU45N06A_T0_00001	TO-251AA	80pcs / Tube	U45N06A	Halogen free
PJP45N06A_T0_00001	TO-220AB	50pcs / Tube	P45N06A	Halogen free
PJF45N06A_T0_00001	ITO-220AB-F	50pcs / Tube	F45N06A	Halogen free

MOUNTING PAD LAYOUT

TO-252AA

Unit: mm



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